






	<h2 style="color: red;">FQP14N15</h2>
	<p>Hersteller-Teilenummer: FQP14N15</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 150V 14.4A TO-220</p> <p>Datenblätter: 1.FQP14N15.pdf 2.FQP14N15.pdf</p> <p>RoHS Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 24470 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP14N15
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 150V 14.4A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	24470 pcs Stock
detaillierte Beschreibung	N-Channel 150V 14.4A (Tc) 104W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	104W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	150V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	14.4A (Tc)
Rds On (Max) @ Id, Vgs	210 mOhm @ 7.2A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	715pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQP14N15 ist neu im Original, Suche FQP14N15 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP14N15 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP14N15: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP140N03L Original FQP140N03L Original</p>	 <p>FQP15N16 Fairchild/ON Semiconductor FQP15N16 FAIRCHILD</p>	 <p>FQP14N30 Fairchild/ON Semiconductor MOSFET N-CH 300V 14.4A TO-220</p>	 <p>FQP14N80C Fairchild/ON Semiconductor FQP14N80C FAIRCHILD</p>
 <p>FQP13N50C_F105 AMI Semiconductor / ON Semiconductor IC POWER MANAGEMENT</p>	 <p>FQP140N03 Fairchild/ON Semiconductor FQP140N03 FAIRCHILD</p>	 <p>FQP14N30 AMI Semiconductor / ON Semiconductor MOSFET N-CH 300V 14.4A TO-220</p>	 <p>FQP13N60C VB FQP13N60C VB</p>

heiße Teile

Mehr

⊗ FQP12N20	↔ FQP12N60	⇒ FQP12N60	D FQP12N60C	↗ FQP12N60C
⊣ FQP12N65C	⊗ FQP12P10	D FQP12P10	⇒ FQP12P20	↗ FQP12P20
⊗ FQP13N06	⊣ FQP13N06	⊗ FQP13N06L	↔ FQP13N06L	↗ FQP13N10
D FQP13N10	⊗ FQP13N10L	⊣ FQP13N10L	⊗ FQP13N50	↗ FQP13N50
⇒ FQP13N50C	↔ FQP13N50C	⊗ FQP13N60C	⊣ FQP140N03	↗ FQP140N03L
↔ FQP14N15	⇒ FQP14N30	D FQP14N30	⊗ FQP14N80	⊣ FQP14N80C
⊗ FQP15N16	D FQP15N30	⇒ FQP15N50	↔ FQP15N60	↗ FQP15N65
⊣ FQP15N80	⊗ FQP15P12	↔ FQP15P12	⇒ FQP16N15	↗ FQP16N15
⊗ FQP16N25	⊣ FQP16N25	⊗ FQP16N25C	D FQP16N25C	↗ FQP17N08
↔ FQP17N08	⊗ FQP17N08L	⊣ FQP17N08L	⊗ FQP17N40	↗ FQP17N40

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